

Reply to Simon's Comment on "Evidence for an Anisotropic State of Two-Dimensional Electrons in High Landau Levels"

Large magneto-transport anomalies of high mobility two-dimensional electron systems in the quantum Hall regime have recently been reported by Lilly *et al.* [1] and subsequently by Du *et al.* [2]. Lilly *et al.* find that when the Fermi level is near half filling of a spin-resolved highly excited Landau level (e.g. at $\nu = 9/2$, $11/2$, etc.), the measured resistivity at very low temperatures ($T < 100$ mK) becomes both highly anisotropic and non-linear. These effects are not seen in the ground ($N = 0$) or first excited ($N = 1$) Landau level, but begin abruptly in the $N = 2$ level and remain clearly evident in several higher levels. At Landau level filling fraction $\nu = 9/2$, Lilly *et al.* found, using a square sample geometry, a resistance anisotropy ratio R_{xx}/R_{yy} of around 60. More recent data, shown in Fig. 1, obtained with a higher mobility square sample having the same contact configuration as in Ref. 1, reveals a ratio of around $R_{xx}/R_{yy} \approx 3500$ at $\nu = 9/2$. These results suggest that a new, and widespread, class of correlated electron states exists in highly excited Landau levels.

Simon [3] finds, via a classical calculation, that the apparent anisotropy observed in square samples can be significantly larger than the intrinsic anisotropy of the microscopic resistivities ρ_{xx} and ρ_{yy} . The origin of this effect is simple: in the presence of anisotropy a current flowing in the "easy" direction, say between two point contacts at the middles of opposite sides of the square, does not spread out as much as it does in an isotropic system. This "channeling" of the current reduces the voltage drop observed between contact placed at the corners of the square. Simon estimates that an intrinsic anisotropy ratio of 7 is sufficient to explain the observed factor of 60. Using his results, we calculate that an intrinsic resistivity anisotropy ratio of about 23 is needed to reconcile the new data shown in Fig. 1.

Simon's results do not challenge the basic fact that transport in highly excited Landau levels becomes extremely anisotropic at very low temperatures. Without microscopic anisotropy his calculation yields macroscopic isotropy. Thus, we find no reason to alter our opinion that the evidence strongly suggests the development of a new correlated electron phase in high Landau levels. The rapid development of both anisotropy and non-linearity as the temperature is reduced below 100 mK and the stark contrast between ground and first excited Landau levels and the $N \geq 2$ levels are only two of the more striking pieces of this evidence. Other indicators of non-trivial many-electron physics include the highly structured magnetic field dependence of the resistivity away from half filling of the third and higher Landau level. As Fig. 1 shows, this structure ultimately manifests itself as deep zeroes in R_{xx} on either side of the anisotropic features around half filling. As Lilly *et al.* reported, the Hall re-

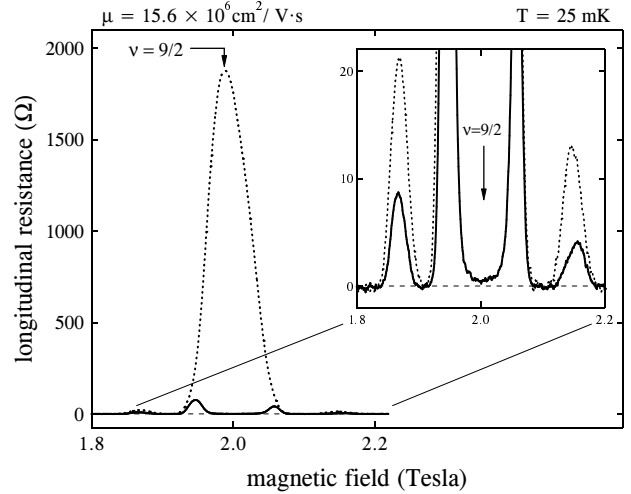


FIG. 1. Longitudinal resistance at $T = 25$ mK around $\nu = 9/2$ for a sample with a very high mobility, $\mu = 15.6 \times 10^6$ cm²/V s, showing an anisotropy ratio of approximately 3500. The two curves represent transport parallel to the $\langle 110 \rangle$ (solid line) and $\langle 1\bar{1}0 \rangle$ (dotted line) crystal axes. Inset: magnified view showing that the resistance minimum at $\nu = 9/2$ in the $\langle 110 \rangle$ direction remains finite down to 25 mK. Away from half-filling deep zeroes in the resistance in both directions develop at 1.90 and 2.10 Tesla. At these fields the Hall resistance shows integer quantized Hall plateaus.

sistance in these regions is quantized, but at the same value as the nearby integer quantized Hall states. This remarkable re-entrance of the quantized Hall effect again points to unusual collective behavior.

M. P. Lilly, K. B. Cooper, and J. P. Eisenstein
California Institute of Technology
Pasadena, CA 91125

L. N. Pfeiffer and K. W. West
Lucent Technologies, Bell Labs
Murray Hill, NJ 07974

-
- [1] M. P. Lilly *et al.*, Phys. Rev. Lett. **82**, 394 (1999).
 - [2] R. R. Du *et al.*, Solid State Comm. **109**, 389 (1999).
 - [3] S. H. Simon, previous comment (cond-mat/9903086).